


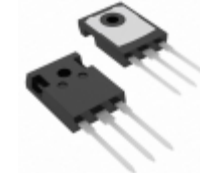
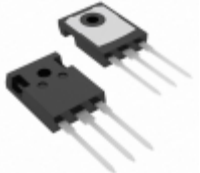

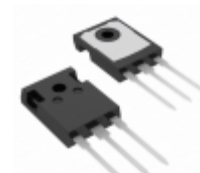



	FGH80N60FDTU	
	Hersteller-Teilenummer:	FGH80N60FDTU
	Hersteller / Marke:	Fairchild/ON Semiconductor
	Teil der Beschreibung:	IGBT 600V 80A 290W TO247
	Datenblätter:	 FGH80N60FDTU.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 32750 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FGH80N60FDTU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	IGBT 600V 80A 290W TO247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	32750 pcs Stock
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	290W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Rückwärts-Erholzeit (Trr)	36ns
Strom - Kollektor (Ic) (max)	80A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	Field Stop
VCE (on) (Max) @ Vge, Ic	2.4V @ 15V, 40A
Strom - Collector Pulsed (Icm)	160A
Schaltenergie	1mJ (on), 520µJ (off)
Gate-Ladung	120nC
Td (ein / aus) bei 25 ° C	21ns/126ns
Testbedingung	400V, 40A, 10 Ohm, 15V
Verpackung	Tube


















FGH80N60FDTU ist neu im Original, Suche FGH80N60FDTU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FGH80N60FDTU Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FGH80N60FDTU: Info@Y-IC.com

Sie können auch interessiert sein:

 FGH80N60FD Original FGH80N60FD Original	 FGH80N60FDTU AMI Semiconductor / ON Semiconductor IGBT 600V 80A 290W TO247	 FGH80N60FD2TU Fairchild/ON Semiconductor IGBT 600V 80A 290W TO247	 FGH80N60UFD Fairchild/ON Semiconductor FGH80N60UFD FAIRCHILD
 FGH80N60FD2TU AMI Semiconductor / ON Semiconductor IGBT 600V 80A 290W TO247	 FGH80N60FD2 FSC FGH80N60FD2 FSC	 FGH80N60RUFD Fairchild/ON Semiconductor FGH80N60RUFD FAIRCHILD	 FGH80N60FD2TU(FGH80N60FD2) FAIRCHILD FGH80N60FD2TU(FGH80N60FD2) FAIRCHILD

heiße Teile

Mehr

 FGH40N60SMDF	 FGH40N60SMDF	 FGH40N60UF	 FGH40N60UFD	 FGH40N60UFDTU
 FGH40N60UFDTU	 FGH40N60UFTU	 FGH40N60UFTU	 FGH40N65UFD	 FGH40N65UFDTU
 FGH40N65UFDTU	 FGH40N6S2	 FGH40N6S2	 FGH40N6S2D	 FGH40N6S2D
 FGH40T100SMD	 FGH40T100SMD	 FGH40T120SMD	 FGH40T120SMD	 FGH40T65SHDF
 FGH40T65SPD	 FGH50N6S2	 FGH50N6S2	 FGH50N6S2D	 FGH50N6S2D
 FGH50T65SQD	 FGH50T65UPD	 FGH50T65UPD	 FGH60N60SF	 FGH60N60SFD
 FGH60N60SMD	 FGH60N60SMD	 FGH60N60UFD	 FGH60N6S2	 FGH60N6S2
 FGH60T65SHD	 FGH75N60SF	 FGH75N60SFTU	 FGH75N60SFTU	 FGH75N60UF
 FGH75N60UFTU	 FGH75N60UFTU	 FGH75T65UPD	 FGH75T65UPD	 FGH80N60FD
 FGH80N60FD2	 FGH80N60FD2TU	 FGH80N60FD2TU	 FGH80N60FDTU	 FGH80N60RUFD

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